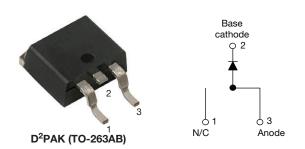


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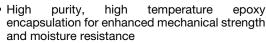
High Performance Schottky Rectifier, 18 A



PRIMARY CHARACTERISTICS							
I _{F(AV)} 18 A							
V_{R}	35 V, 40 V, 45 V						
V _F at I _F	0.53 V						
I _{RM}	25 mA at 125 °C						
T _J max.	175 °C						
E _{AS}	24 mJ						
Package	D ² PAK (TO-263AB)						
Circuit configuration	Single						

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- AEC-Q101 qualified
- Meets JESD 201 class 1 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

DESCRIPTION

The VS-18TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL CHARACTERISTICS VALUES UNI									
I _{F(AV)}	Rectangular waveform	18	Α						
V _{RRM}	Range	35 to 45	V						
I _{FSM}	$t_p = 5 \mu s sine$	1800	Α						
V _F	18 A _{pk} , T _J = 125 °C	0.53	V						
T _J	Range	-55 to 175	°C						

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-18TQ035SHM3	VS-18TQ040SHM3	VS-18TQ045SHM3	UNITS			
Maximum DC reverse voltage	V_{R}	35	40	45	V			
Maximum working peak reverse voltage	V_{RWM}	33	40	45	V			

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDI	VALUES	UNITS				
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 149 °C	18	Α				
Maximum peak one cycle	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	1800				
non-repetitive surge current See fig. 7		10 ms sine or 6 ms rect. pulse	390	Α				
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 3.6 \text{A}, L = 3.7 \text{mH}$		24	mJ			
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3.6	А			



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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS				
Maximum forward voltage drop See fig. 1		18 A	T _{.1} = 25 °C	0.60			
	V _{FM} ⁽¹⁾	36 A	11 = 23 0	0.72	V		
		18 A	T _{.1} = 125 °C	0.53			
		36 A	- IJ = 123 C	0.67			
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V_{R} = Rated V_{R}	2.5	mA		
See fig. 2		T _J = 125 °C	VR = nateu VR	25	IIIA		
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz), 25 °C		1400	pF		
Typical series inductance	L _S	Measured lead to lead 5	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs			

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS			
Maximum junction and storage temperature ran	ge	T _J , T _{Stg}		-55 to 175	°C			
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	1.50	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	G/VV			
Annewimete weight				2	g			
Approximate weight				0.07	oz.			
May enting toward	minimum			6 (5)	kgf · cm			
Mounting torque maximur				12 (10)	(lbf · in)			
				18TQ0)35SH			
Marking device			Case style D ² PAK (TO-263AB)	18TQ0)40SH			
)45SH			

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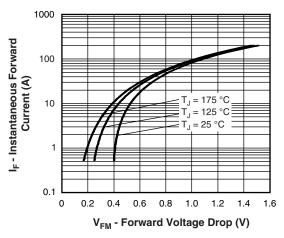


Fig. 1 - Maximum Forward Voltage Drop Characteristics

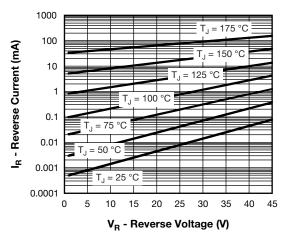


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

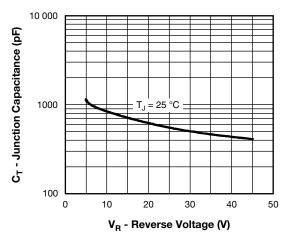


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

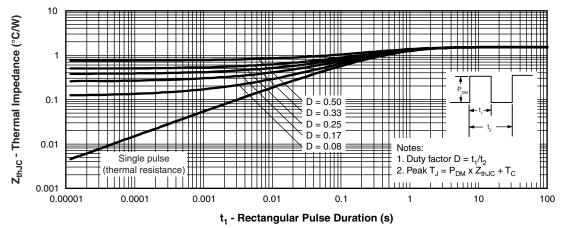


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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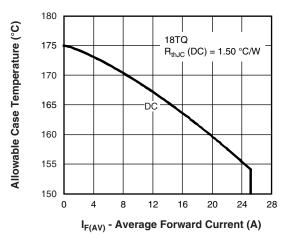


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

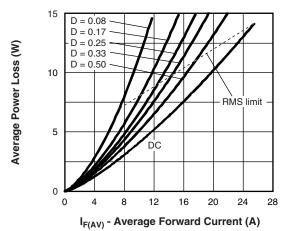


Fig. 6 - Forward Power Loss Characteristics

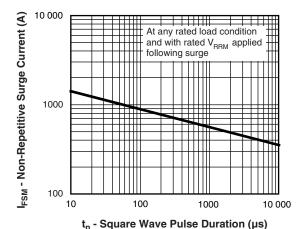


Fig. 7 - Maximum Non-Repetitive Surge Current

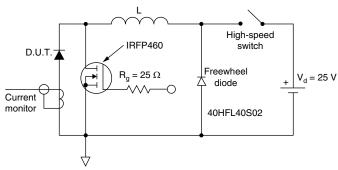
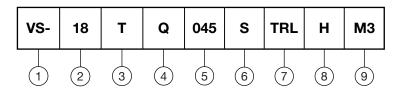


Fig. 8 - Unclamped Inductive Test Circuit

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (18 A)

Circuit configuration: T = TO-220

- Schottky "Q" series 035 = 35 V

- Voltage ratings — 040 = 40 V 045 = 45 V

- $S = D^2PAK (TO-263AB)$

- S = D-PAK (10-263AE - None = tube

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

8 - H = AEC-Q101 qualified

9 - M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-18TQ035SHM3	50	1000	Antistatic plastic tubes						
VS-18TQ035STRRHM3	800	800	13" diameter reel						
VS-18TQ035STRLHM3	800	800	13" diameter reel						
VS-18TQ040SHM3	50	1000	Antistatic plastic tubes						
VS-18TQ040STRRHM3	800	800	13" diameter reel						
VS-18TQ040STRLHM3	800	800	13" diameter reel						
VS-18TQ045SHM3	50	1000	Antistatic plastic tubes						
VS-18TQ045STRRHM3	800	800	13" diameter reel						
VS-18TQ045STRLHM3	800	800	13" diameter reel						

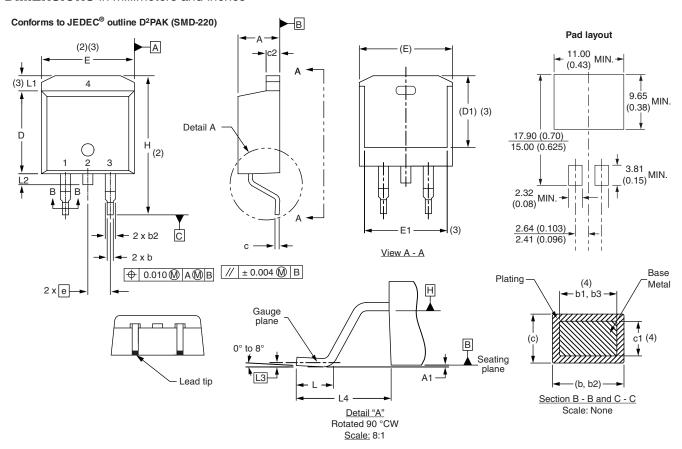
LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?95046</u>						
Part marking information	www.vishay.com/doc?95444					
Packaging information	www.vishay.com/doc?95032					
SPICE model	www.vishay.com/doc?96209					



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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	INCHES		NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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